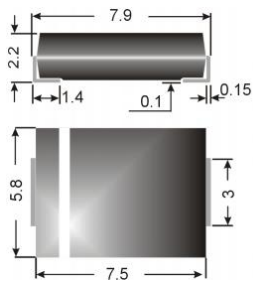


S5 A ... S5 M



Surface mount diode

Standard silicon rectifier diodes

S5 A...S5 M

Forward Current: 5 A

Reverse Voltage: 50 to 1000 V

Features

- Max. solder temperature: 260°C
- Plastic material has UL classification 94V-0

Mechanical Data

- Plastic case SMC / DO-214AB
- Weight approx.: 0,21 g
- Terminals: plated terminals solderable per MIL-STD-750
- Mounting position: any
- Standard packaging: 3000 pieces per reel

1) Max. temperature of the terminals $T_T = 100\text{ °C}$

2) $I_F = 5\text{ A}$, $T_J = 25\text{ °C}$

3) $T_A = 25\text{ °C}$

4) Mounted on P.C. board with 60 mm² copper pads at each terminal

Type	Polarity color band	Repetitive peak reverse voltage V_{RRM} V	Surge peak reverse voltage V_{RSM} V	Maximum forward voltage $T_J = 25\text{ °C}$ $I_F = 5\text{ A}$ $V_F^{(2)}$ V	Maximum reverse recovery time $I_F = -\text{A}$ $I_R = -\text{A}$ $I_{RR} = -\text{A}$ t_{rr} ns
S5 A	-	50	50	1,15	-
S5 B	-	100	100	1,15	-
S5 D	-	200	200	1,15	-
S5 G	-	400	400	1,15	-
S5 J	-	600	600	1,15	-
S5 K	-	800	800	1,15	-
S5 M	-	1000	1000	1,15	-

Absolute Maximum Ratings		$T_A = 25\text{ °C}$, unless otherwise specified	
Symbol	Conditions	Values	Units
I_{FAV}	Max. averaged fwd. current, R-load, $T_T = 100\text{ °C}$	5	A
I_{FRM}	Repetitive peak forward current $f > 15\text{ Hz}^1)$	50	A
I_{FSM}	Peak fwd. surge current 50 Hz half sinus-wave ³⁾	225	A
I^2t	Rating for fusing, $t < 10\text{ ms}^3)$	300	A ² s
R_{thA}	Max. thermal resistance junction to ambient ⁴⁾	50	K/W
R_{thT}	Max. thermal resistance junction to terminals	15	K/W
T_J	Operating junction temperature	-50...+150	°C
T_s	Storage temperature	-50...+150	°C

Characteristics		$T_A = 25\text{ °C}$, unless otherwise specified	
Symbol	Conditions	Values	Units
I_R	Maximum leakage current, $T_J = 25\text{ °C}$; $V_R = V_{RRM}$	10	µA
	$T_J = 125\text{ °C}$; $V_R = V_{RRM}$	250	µA
C_J	Typical junction capacitance (at MHz and applied reverse voltage of V)	-	pF
Q_{rr}	Reverse recovery charge ($U_R = V$; $I_F = A$; $dI_F/dt = A/ms$)	-	µC
E_{RSM}	Non repetitive peak reverse avalanche energy ($I_R = mA$; $T_J = \text{°C}$; inductive load switched off)	-	mJ

